



# **AFC**PLUS

high accuracy
Die & Flip Chip Bonder

AFC
Precision of
Assembly +/- 0.5 µm



- Modular machine concept
- +/- 0.5µm placement accuracy
- · Flip-chip option
- · Assembly of chip and micro-optics
  - WDM, optoelectronic components, micro-lenses, micro- mechanics
- Auto Loading for Substrate Wafer
- · Wafer mapping
- · Epoxy stamping and dispensing
- Eutectic bonding via diode-laser or heatingplate
- Passive alignment
- Active alignment on request
- Active bond-force-control
- Postbond inspection / measurement
- UV-Curing (option)





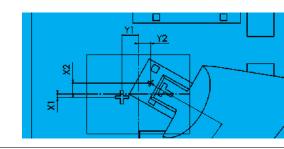
## Laser and Eutectic Soldering

- Adjustable heating courses with high soldering temperatures (up to 600°)
- Shortest soldering time (<1s)
- Best yield and high quality by repeatability of laser soldering
- Hot pick up tool (up to 350°C)



# Technical Concept

- Relative positioning
- Substrate and chip position measured during alignement with the same camera system



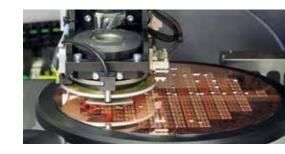
#### **Precision Components**

- Vibration damping due granite base design
- High precision stages driven by AC motors
- Precision vision system with high resolution CCD-cameras
- High accuracy bondhead
- Flip-Chip-Unit
- Wafer, Wafflepack, Gel-Pak



#### Passive alignment

- Permanent observation of the components through stationary high resolution cameras
- Controlling the position during alignment and setting process
- Die alignment to active components (e.g. microlenses to energized laserchip)
- Die alignment to fiducial marks (e.g. V-groove)
- Flipped Die alignment through up- and down-side correlation



### **Technical Informations**

Gerneral			
control	multi-axis-controller		
operating system	Windows 7		
programming	keyboard and graphic display / touch display		
operator interface	menu driven, English		
data transfer	ethernet TCP/IP , electronic connection: 10		
auta transier	Base T, 10 Mbit/s		
Equipment			
BONDHEAD TRANSFER S	VSTEM		
function	moves bondhead from source side (chip side) to destination side (substrate side)		
coarse X axis positioning	linear motor driven, high velocity and acceleration noncontact linear encoder, resolution 0,1 µm		
Z axis	AC servo drive, noncontact linear encoder, resolution 1µm		
BONDING STAGE FOR SUBSTRATE			
XY axis	AC or stepper motor driven, open-frame design		
	(optional linear motor)		
range of XY axis	300 x 300 mm		
optinal: rotations Axis	stepper motor-driven, 360°,		
COURCE TARLE FOR WAS	resolution 0.01°		
SOURCE TABLE FOR WAF	<del></del> -		
	AC or stepper motor driven, open-frame design (optional linear motor)		
range of XY axis	300 x 300 mm		
optional: rotations axis	stepper motor-driven, 360°,		
	resolution 0.01°		
CAMERA AXIS			
Z axis (focussing)	resolution 0.01°  AC servo drive, resolution 1 µm		
Z axis (focussing) BOND HEAD	AC servo drive, resolution 1 μm		
Z axis (focussing) BOND HEAD function	AC servo drive, resolution 1 µm  design for active adjustment; high accuracy positioning; bondforce controlling		
Z axis (focussing) BOND HEAD function XY axis	AC servo drive, resolution 1 µm  design for active adjustment; high accuracy positioning; bondforce controlling piezo driven; resolution 0.1µm; range 400µm x 400µm		
Z axis (focussing) BOND HEAD function  XY axis rotation axis	AC servo drive, resolution 1 µm  design for active adjustment; high accuracy positioning; bondforce controlling piezo driven; resolution 0.1µm; range 400µm x 400µm 360°, resolution 0.001°		
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Z axis (focussing) BOND HEAD function  XY axis rotation axis bond force  touch sensor	AC servo drive, resolution 1 µm  design for active adjustment; high accuracy positioning; bondforce controlling piezo driven; resolution 0.1µm; range 400µm x 400µm 360°, resolution 0.001° programmable, standard working area 3 -2000 g; resolution 0.5 g (other working area available) determines first mechanical contact		
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Lasersystem	
function	for fast eutectic bonding with controlled heat
technique	fiber-coupled high power laser with focussing optic
max. output power	45 W / 75 W / 100 W
center wavelength	808 nm (+-10%) other wavelength on request
temperature	programmable, range: up to 400° C; online measurement phyrometer
pulsetime	free programmable profike controlled by power and temperature

programmable

Image Recognition	
vision System	COGNEX
focussing	programmable; optional autofocus function during programming
recognition methods	standard vision tools; special filter for micro stuctures
pattern recognition	programmable windows and models

Amicra follows a policy of continuous product improvement. Specifications are subject to change without notice. Version April 2013

ejection speed



#### SOURCE CAMERA (MATERIAL SIDE E.G. LASERCHIP)

Example		
CCD camera	1/ 1.8 "	2MP

magnification 5x; other magnification on request

field of view approx. 1,3 x 1 mm<sup>2</sup>

coaxial lighting; LED or halogen, optional RGB illumination coaxial lighting; I
DESTINATION CAMERA (SUBSTRAT SIDE)

Example CCD camera 1 / 1.8" 2MPx magnification 5x; other maginification on request field of view /FOV/Pixel approx. 1,3 x 1 mm<sup>2</sup> approx. 0,8 µm/Pixel at 1/2" CCD-chip resolution coaxial lighting; LED or halogen, optional RGB

illumination **UPWARD CAMERA** FOR FLIP CHIP CORRELATION

Example CCD camera 1 / 1.8" 2MPx

magnification 5x; other maginification on request

field of view /FOV/ Pixe approx. 1,3 x 1 mm<sup>2</sup>

approx. 0,8 µm/Pixel at 1/2" CCD-chip coaxial lighting; LED or halogen, optional RGB resolution illumination

#### Dimensions/ Power ratings

size (WxDxH), weight 1400 x 1200 x 1700 mm, 2100 kg - 0.8 bar, Throughput: 3 m3/h vacuum compressed air 5 bar dry and oilfree air nitrogen 1 bar electrical power ratings distribution voltage: 400 V opt. 230 V/115V ambient temperature 18 to 25 °C non-condensing relative humidity

Capacity Ratings module-specific cycle time module-specific cycle time for flip-chip process throughput machine availability accuracy

20 s depending on configuration and

20 s depending on configuration and application

up to 200 components/h device dependent >95% +/- 0.5 µm@3s



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